

Schottky Barrier Diodes

These Schottky barrier diodes are designed for high speed switching applications, circuit protection, and voltage clamping. Extremely low forward voltage reduces conduction loss. Miniature surface mount package is excellent for hand held and portable applications where space is limited.

- Extremely Fast Switching Speed
- Low Forward Voltage — 0.35 Volts (Typ) @ $I_F = 10 \text{ mA}$

Features

We declare that the material of product compliance with RoHS requirements.

ORDERING INFORMATION

Device	Marking	Shipping
LBAT54ALT1G	B6	3000/Tape & Reel
LBAT54ALT3G	B6	10000/Tape & Reel

DEVICE MARKING

LBAT54ALT1G = B6

MAXIMUM RATINGS ($T_J = 125^\circ\text{C}$ unless otherwise noted)

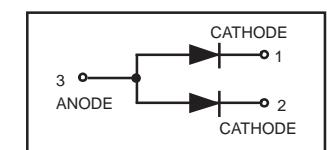
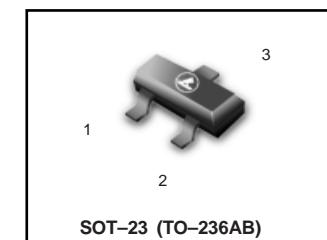
Rating	Symbol	Max	Unit
Reverse Voltage	V_R	30	Volts
Forward Power Dissipation @ $T_A = 25^\circ\text{C}$	P_F	225	mW
Derate above 25°C		1.8	$\text{mW}/^\circ\text{C}$
Forward Current(DC)	I_F	200Max	mA
Junction Temperature	T_J	125Max	$^\circ\text{C}$
Storage Temperature Range	T_{stg}	-55 to +150	$^\circ\text{C}$

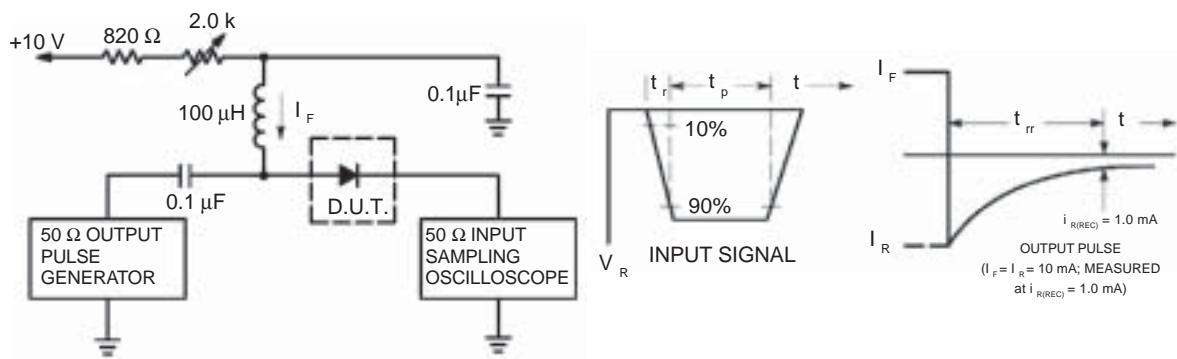
ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted) (EACH DIODE)

Characteristic	Symbol	Min	Typ	Max	Unit
Reverse Breakdown Voltage ($I_R = 10 \mu\text{A}$)	$V_{(BR)R}$	30	—	—	Volts
Total Capacitance ($V_R = 1.0 \text{ V}$, $f = 1.0 \text{ MHz}$)	C_T	—	—	10	pF
Reverse Leakage ($V_R = 25 \text{ V}$)	I_R	—	0.5	2.0	μA
Forward Voltage ($I_F = 0.1 \text{ mA}$)	V_F	—	0.22	0.24	Vdc
Forward Voltage ($I_F = 30 \text{ mA}$)	V_F	—	0.41	0.5	Vdc
Forward Voltage ($I_F = 100 \text{ mA}$)	V_F	—	0.52	1.0	Vdc
Reverse Recovery Time ($I_F = I_R = 10 \text{ mA}$, $I_{R(REC)} = 1.0 \text{ mA}$, Figure 1)	t_{rr}	—	—	5.0	ns
Forward Voltage ($I_F = 1.0 \text{ mA}$)	V_F	—	0.29	0.32	Vdc
Forward Voltage ($I_F = 10 \text{ mA}$)	V_F	—	0.35	0.40	Vdc
Forward Current (DC)	I_F	—	—	200	mA
Repetitive Peak Forward Current	I_{FRM}	—	—	300	mA
Non-Repetitive Peak Forward Current ($t < 1.0 \text{ s}$)	I_{FSM}	—	—	600	mA

LBAT54ALT1G

30 VOLTS SCHOTTKY BARRIER
DETECTOR AND SWITCHING
DIODES



LBAT54ALT1G


- Notes:
1. A 2.0 kΩ variable resistor adjusted for a Forward Current (I_F) of 10mA.
 2. Input pulse is adjusted so $I_{R(\text{peak})}$ is equal to 10mA.
 3. $t_p \gg t_{rr}$

Figure 1. Recovery Time Equivalent Test Circuit

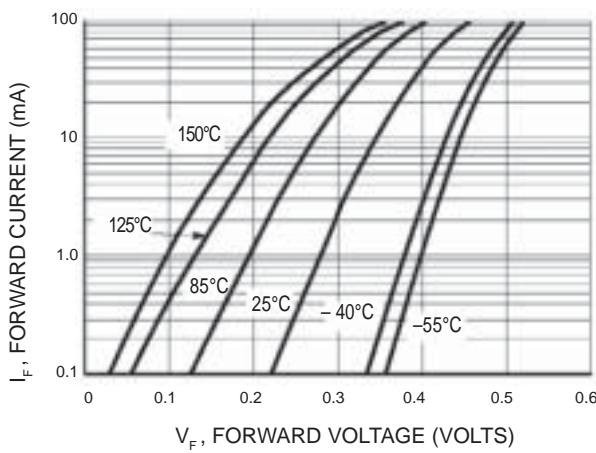


Figure 2. Forward Voltage

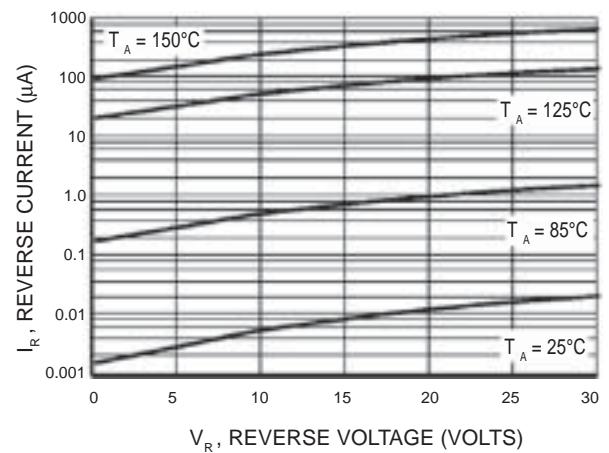


Figure 3. Leakage Current

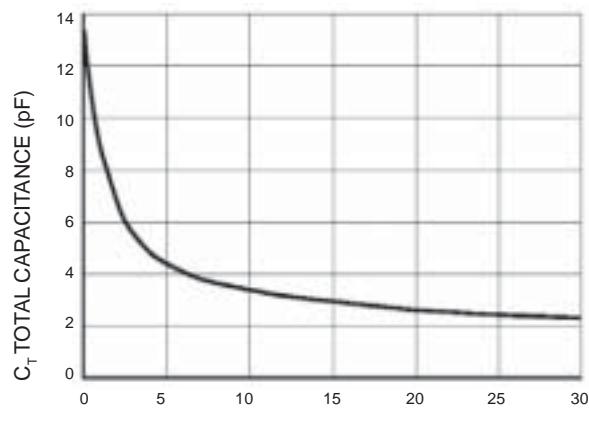
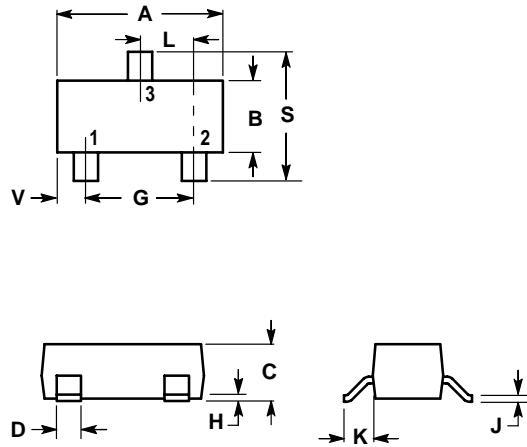


Figure 4. Total Capacitance

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SOT-23

NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.1102	0.1197	2.80	3.04
B	0.0472	0.0551	1.20	1.40
C	0.0350	0.0440	0.89	1.11
D	0.0150	0.0200	0.37	0.50
G	0.0701	0.0807	1.78	2.04
H	0.0005	0.0040	0.013	0.100
J	0.0034	0.0070	0.085	0.177
K	0.0140	0.0285	0.35	0.69
L	0.0350	0.0401	0.89	1.02
S	0.0830	0.1039	2.10	2.64
V	0.0177	0.0236	0.45	0.60

